

MD2009DFP

High voltage NPN power transistor for CRT TV

Features

- State-of-the-art technology:
 - diffused collector "enhanced generation"
- Stable performance versus operating temperature variation
- Low base drive requirement
- Tight h_{FE} range at operating collector current
- Fully isolated power package UL compliant
- Integrated free wheeling diode

Application

Horizontal deflection output for CRT TV

Description

The MD2009DFP is manufactured using diffused collector in planar technology adopting new and enhanced high voltage structure. The new MD product series show improved silicon efficiency bringing updated performance to the horizontal deflection stage.

TO-220FP

Figure 1. Internal schematic diagram

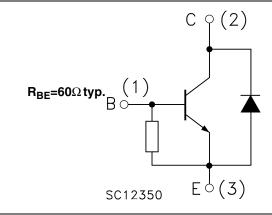


Table 1. Device summary

Order code		Marking	Package	Packaging
	MD2009DFP	MD2009DFP	TO-220FP	Tube

1 Electrical ratings

Table 2.	Absolute	maximum	ratings
	Absolute	maximum	raungs

Symbol	Parameter	Value	Unit
-,			
V _{CES}	Collector-emitter voltage (V _{BE} = 0)	1500	V
V _{CEO}	Collector-emitter voltage $(I_B = 0)$	700	V
V _{EBO}	Base-emitter voltage (I _C = 0)	7	V
۱ _C	Collector current	10	А
I _{CM}	Collector peak current (t _P < 5ms)	16	А
۱ _B	Base current	6	А
P _{TOT}	Total dissipation at $T_c = 25^{\circ}C$	40	W
V _{ISO}	Isolation withstand voltage (RMS) from all three leads to external heatsink	2500	v
T _{stg}	Storage temperature	-65 to 150	ာ
Τ _J	Max. operating junction temperature	150	Ŭ

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	3.12	°C/W



2 Electrical characteristics

(T_{case} =25°C unless otherwise specified)

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 1500V V _{CE} = 1500V, T _c = 125°C			0.2 2	mA mA
I _{EBO}	Emitter cut-off current $(I_C = 0)$	V _{EB} = 5V	40		120	mA
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = 700mA	10			v
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_{\rm C} = 5.5 {\rm A}$, $I_{\rm B} = 1.4 {\rm A}$			2.8	V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	$I_{\rm C} = 5.5 {\rm A}$, $I_{\rm B} = 1.4 {\rm A}$			1.3	V
h _{FE} ⁽¹⁾	DC current gain	$ \begin{array}{ll} I_{C} = 1A, & V_{CE} = 5V \\ I_{C} = 5.5A, & V_{CE} = 1V \\ I_{C} = 5.5A, & V_{CE} = 5V \end{array} $	5	18 4.7	7	
V _F ⁽¹⁾	Diode forward voltage	I _F = 5.5 A			1.6	V
t _s t _f	Inductive load Storage time Fall time	$\begin{split} I_C &= 5\text{A}, f_h = 16\text{KHz} \\ I_{B(on)} &= 1.5\text{A}, V_{BE(off)} = -2.7\text{V} \\ I_{BB(off)} &= 6.2\mu\text{H} \end{split}$		4.5 0.3	6 0.6	μs μs

Table 4. Electrical characteristics

1. Pulse test: pulse duration \leq 300 µs, duty cycle \leq 2%.



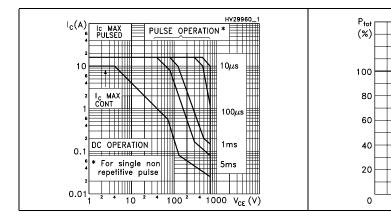
DG11570

100 125 T_{case}(°C)

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

Figure 3. Derating curve





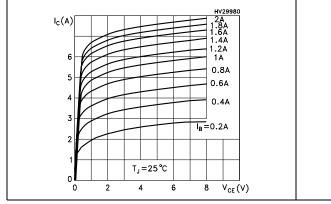
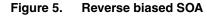
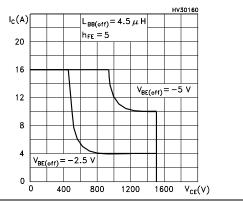
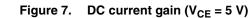


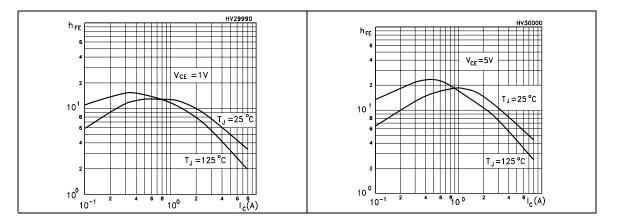
Figure 6. DC current gain ($V_{CE} = 1 V$)



25 50 75









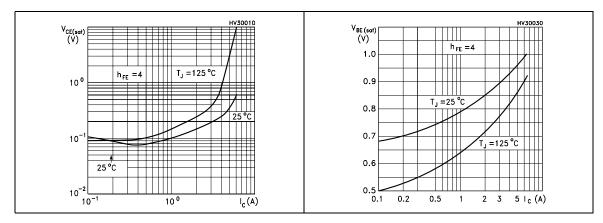
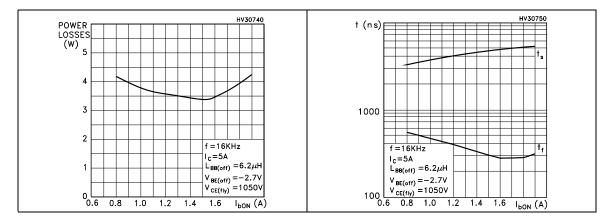


Figure 8. Collector-emitter saturation voltage Figure 9. Base-emitter saturation voltage



Figure 11. Inductive load switching time





3 Test circuits

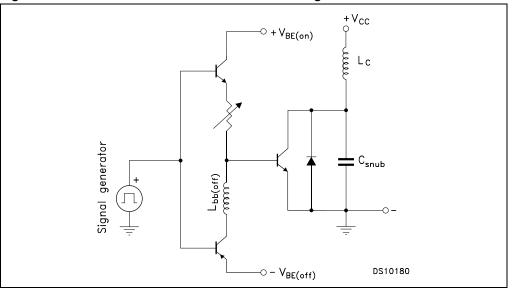
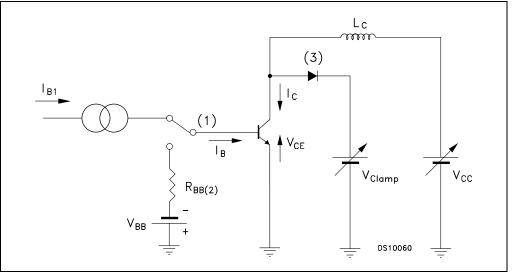


Figure 12. Power losses and inductive load switching test circuit





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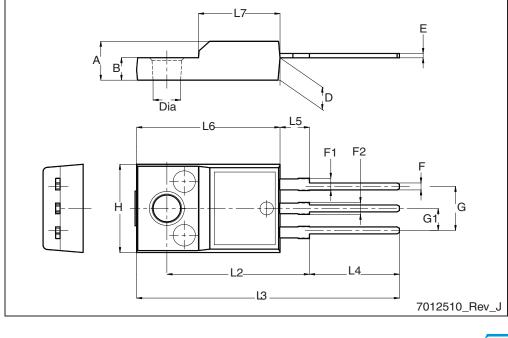


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.



TO-220FP mechanical data					
Dim	mm				
Dim.	Min.	Тур.	Max.		
A	4.4		4.6		
В	2.5		2.7		
D	2.5		2.75		
E	0.45		0.7		
F	0.75		1		
F1	1.15		1.70		
F2	1.15		1.5		
G	4.95		5.2		
G1	2.4		2.7		
н	10		10.4		
L2		16			
L3	28.6		30.6		
L4	9.8		10.6		
L5	2.9		3.6		
L6	15.9		16.4		
L7	9		9.3		
Dia	3		3.2		



8/1	n
0/1	v

5 Revision history

Table 5.Document revision history

Date	Revision	Changes
11-Aug-2009	1	First release



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